

## 8.0 to 18.0 GHz YIG-TUNED GaAs FET OSCILLATORS

### Highly Reliable State-of-the-Art Thin-Film Technology

OMNIYIG's 8 to 18 GHz oscillators employ thin-film technology, coupled with GaAs FET transistors, and were designed using Computer Aided Design to provide highly reliable state-of-the-art performance.

#### 10 and 30 mW and Higher RF Power Outputs

Two versions - 10 mW and 30 mW - are available, and each oscillator can be furnished in either a mini-cube or cylindrical package to meet your system's electrical and mechanical requirements, or other package.

#### Advanced Electrical Performance

Electronically tunable over the entire 8 to 18 GHz frequency range, these oscillators feature advanced coupling techniques to provide the highest power outputs available in the industry with the lowest second harmonic and spurious responses.

#### Superb Linearity - Better Than $\pm 12.5$ MHz

OMNIYIG's proprietary magnetic circuit, and the coupling technique used between YIG sphere and active element, make the linearity of these oscillators better than  $\pm 12.5$  MHz.

#### With or Without Driver

Oscillators can be furnished stand-alone, or with integrated analog or digital drivers. A typical analog driver control input of 0 to 10 volts tunes the oscillator over the full frequency band. OMNIYIG's integrated 12-bit D to A converter allows you to step frequency in small increments using a TTL input.

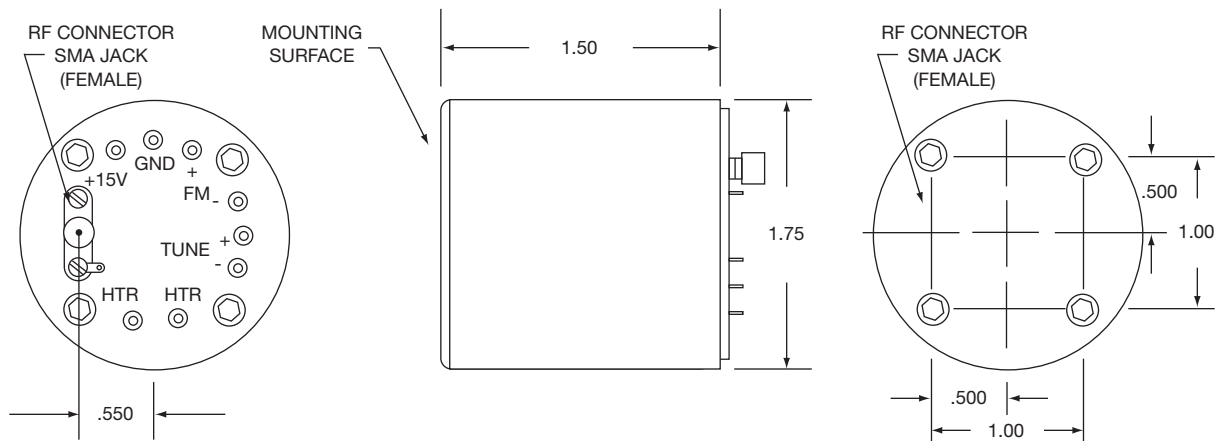
#### Commercial or Military Use

Our standard oscillators are specified to operate from -20 to +65°C. However, all of OMNIYIG's products can be furnished to military specifications such as MIL-E-5400 class II/MIL-STD-883. OMNIYIG provides comprehensive environmental testing to insure compliance to these requirements.

#### Quality Assurance

Our Quality Assurance department maintains all documents in conformance to MIL-I-45208, and a calibration system to control and certify measurement accuracy in accordance with MIL-C-455662A.

### OUTLINE DIMENSIONS



## ELECTRICAL SPECIFICATIONS

Model Number	UNITS	YOM818-10A	YOM818-30A
		YOM818-10B	YOM818-30B
Frequency Range	GHz	8.0 - 18.0	8.0 - 18.0
RF Power Output (Minimum)	mW	10	30
RF Power Output Variation	dB	±5	±5
Pulling figure (VSWR 1.5:1)	MHz	±6	±6
Second Harmonic	dBc	-12	-12
Other Spurious Signals	dBc	>50	>50
Frequency Drift (-20° to +65°C)	MHz	±.01%/°C	±.01%/°C
Tuning Linearity	MHz	±12.5	±12.5
Hysteresis	MHz	10	10
Tuning Speed (full band w/in 6MHz final freq)	mSec	13	13
Tuning Sensitivity (Typical)	MHz/mA	20	20
Coil Resistance (Typical)	ohm	10	10
Coil Inductance (Typical)	mH	100	100

## MECHANICAL SPECIFICATIONS, all model numbers

Dimensions	1.75" x 1.5" cyl.	1.75" x 1.5" cyl.
Output RF Connector (female or male)	3 mm	3 mm
DC Connector	Solder Pins	Solder Pins
Weight	20 oz	20 oz
Mounting (Tapped Holes x 4)	6-32 Tapped Holes	6-32 Tapped Holes
Drawing	YOM818-10A: 82457 YOM818-30A: 82457	YOM818-10B: 82458 YOM818-30B: 82458

## POWER SUPPLY REQUIREMENTS, all model numbers

Oscillator Supply	+15 Vdc @ 300 mA Operating (typical)
Heater Supply	20 - 30 Vdc @ 50 mA, Steady State

### NOTES:

1. Each oscillator will have test data sheet and the exact voltage will be indicated.
2. YIG drivers for the above models are supplied in one integral package with oscillator.
3. Driver control voltage is typically 0-10 volts—for digital; 12-bit driver also available.
4. Other frequency ranges are available upon request.
5. Higher power outputs are also available.